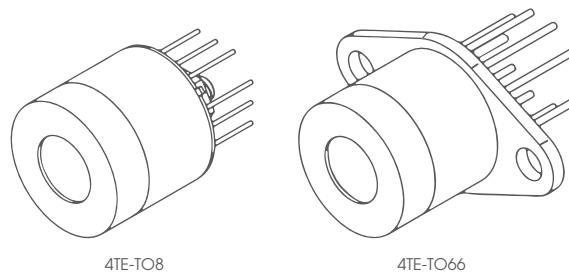


PC-10.6 SERIES

HgCdTe thermoelectrically cooled photoconductive infrared detectors



FEATURES

- Spectral range: over 10.3 μm
- Front-side illuminated
- No minimum order quantity required

RELATED PRODUCTS

- **LabM-I-10.6** detection module (p. 107)
- **UM-I-10.6** detection module (p. 113)
- **microM-10.6** detection module (p. 110)
- **PVIA-10.6-1x1-T039-NW-36**
RoHS-compliant detector (p. 22)
- **PVIA-4TE-10.6-1x1-T08-wZnSeAR-36**
RoHS-compliant detector (p. 22)

APPLICATIONS

- Gas detection, monitoring and analysis: SO_2 , NH_3 , SF_6
- CBRN threats detection
- CO_2 laser measurements: power monitoring and control, beam profiling and positioning, calibration
- Free-space optical communication
- FTIR spectroscopy
- Medical bacteria identification
- Dentistry
- Glucose sensing

SERIES DESCRIPTION

Detector symbol	Cooling (p. 191)	Temperature sensor (p. 192)	Active area, A, mm \times mm	Optical immersion	Package	Acceptance angle, ϕ , deg.	Window (p. 193)
PC-4TE-10.6-1x1-T08-wZnSeAR-70	4TE $T_{\text{chip}} \approx 200\text{K}$	thermistor	1x1	no	TO8	~70	wZnSeAR (3 deg. zinc selenide, anti-reflection coating)
PC-4TE-10.6-1x1-T066-wZnSeAR-70					TO66		

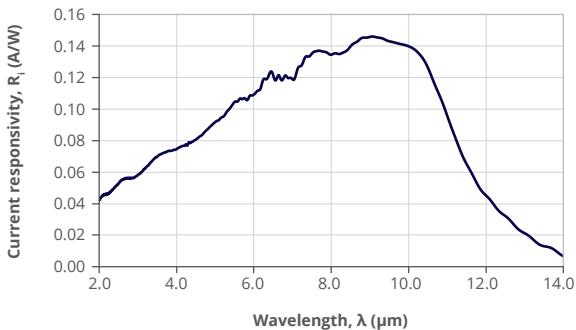
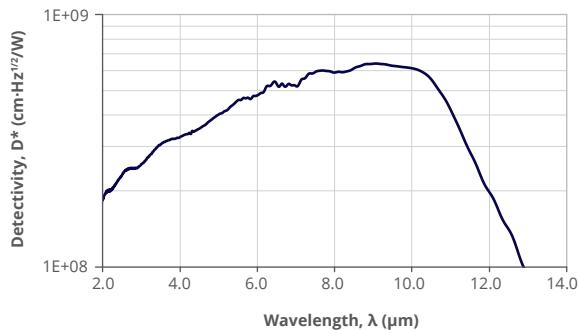
SPECIFICATION ($T_{\text{amb}} = 293\text{ K}$, $V_b = 0.4\text{ V}$)

Detector symbol	Peak wavelength	Specific wavelength	Cut-off wavelength (10%)	Detectivity			Current responsivity			Time constant	Dynamic resistance	Bias voltage	$1/f$ corner frequency
				λ_{peak}	λ_{spec}	$\lambda_{\text{cut-off}}$	$D^*(\lambda_{\text{peak}}, 20\text{kHz})$	$D^*(\lambda_{\text{spec}}, 20\text{kHz})$	$R(\lambda_{\text{peak}})$	$R(\lambda_{\text{spec}})$	τ	R	V_b
PC-4TE-10.6-1x1-T08-wZnSeAR-70	8.5±0.6	10.6	13	6.5×10 ⁸	3.5×10 ⁸	4.0×10 ⁸	0.06	0.03	0.06	30	250	0.4	20
PC-4TE-10.6-1x1-T066-wZnSeAR-70													

SPECTRAL RESPONSE (Typ., $T_{\text{amb}} = 293 \text{ K}$)

PC-4TE-10.6-1x1-T08/TO66-wZnSeAR-70

PC-4TE-10.6-1x1-T08/TO66-wZnSeAR-70



MECHANICAL LAYOUT AND PINOUT

- 4TE package
 - Technical drawing (p. 209)
- 4TE-T066 package
 - Technical drawing (p. 211)

RECOMMENDED AMPLIFIERS

Detector symbol	Amplifier type
PC-4TE-10.6-1x1-T08-wZnSeAR-70	AIP series (p. 126) PIP series (p. 129) MIP series (p. 132) SIP-T08 series (p. 135)

ABSOLUTE MAXIMUM RATINGS

Parameter	Test conditions/remarks	Value	Unit
Ambient operating temperature, T_{amb}	Operation at $T_{\text{amb}} > 30^\circ\text{C}$ may increase the active element temperature and reduce the performance of the detector below specified parameters	-20 to 30	°C
Storage temperature, T_{stg}		-20 to 50	°C
Soldering temperature	Within 5 s or less	≤ 300	°C
Storage humidity	No dew condensation	10 to 90	%
Maximum incident optical power density	Continuous wave (CW) or single pulses > 1 μs duration	100	W/cm ²
	Single pulses < 1 μs duration	1	MW/cm ²
Maximum bias voltage, $V_{\text{b max}}$		2.0	V
Maximum TEC voltage, $V_{\text{TEC max}}$	4TE	8.3	V
Maximum TEC current, $I_{\text{TEC max}}$	4TE	0.4	A

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. Constant or repeated exposure to absolute maximum rating conditions may affect the quality and reliability of the device.